

Surface Mount Ultra Low IR Schottky Barrier Rectifier

Voltage

150 V

Current

10 A

Features

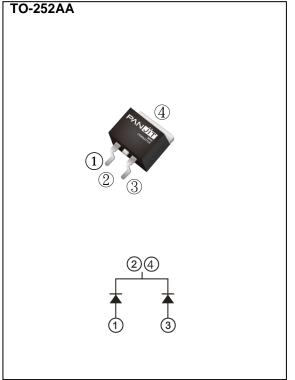
- Low leakage current
- Ideal for automated placement
- Low power loss, high efficiency
- High surge current capability
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: TO-252AA Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.3217 grams



Maximum Ratings and Thermal Characteristics (T_A = 25 °C unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS		
Maximum Repetitive Peak Reverse Voltage		V_{RRM}	150	V	
Maximum RMS Voltage		V _{RMS}	105	V	
Maximum DC Blocking Voltage		V _{DC}	150	V	
Maximum Average Forward Current	per device	I=mo	10	А	
	per diode	I _{F(AV)}	5		
Peak Forward Surge Current : 8.3 ms Single H	I _{FSM}	120	А		
Wave Superimposed On Rated Load Typical Junction Capacitance	С	130	pF		
Measured at 1 MHZ And Applied V _R = 4 V		130			
Typical Thermal Resistance per diode	(Note 1)	RθJA	50		
	(Note 2)	Rелс	6.8	°C/W	
	(Note 2)	RθJL	5.1		
Operating Junction Temperature Range		TJ	-55~175	°C	
Storage Temperature Range		T _{STG}	-55~175	°C	



Electrical Characteristics (T_A = 25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Forward Voltage Per Diode	V _F	I _F = 1 A, T _J = 25 °C	-	0.67	0.72		
		I _F = 3 A, T _J = 25 °C	-	0.75	0.8	V	
		I _F = 5 A, T _J = 25 °C	-	0.79	0.85		
		I _F = 1 A, T _J = 125 °C	-	0.52	0.57		
		I _F = 3 A, T _J = 125 °C	-	0.61	0.66		
		I _F = 5 A, T _J = 125 °C	-	0.66	0.71		
Reverse Current Per Diode ^(Note 3)	I _R	V _R = 120 V, T _J = 25 °C	-	0.02	0.3		
		V _R = 150 V, T _J = 25 °C	-	0.06	5	uA	
		V _R = 150 V, T _J = 125 °C	-	45	400		

NOTES:

- 1. Mounted on a FR4 PCB, single-sided copper, standard footprint.
- 2. Mounted on a FR4 PCB, single-sided copper, with 100 cm² copper pad area.
- 3. Short duration pulse test used to minimize self-heating effect.



TYPICAL CHARACTERISTIC CURVES

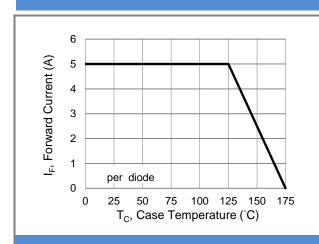


Fig.1 Forward Current Derating Curve

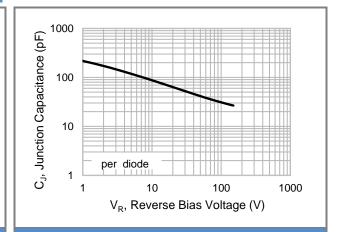


Fig.2 Typical Junction Capacitance

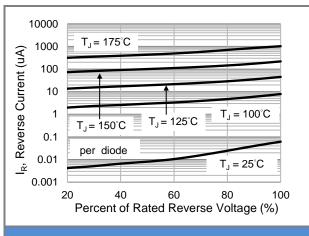


Fig.3 Typical Reverse Characteristics

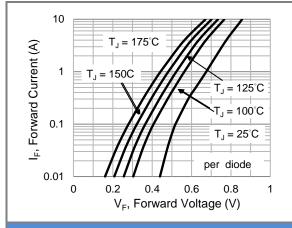


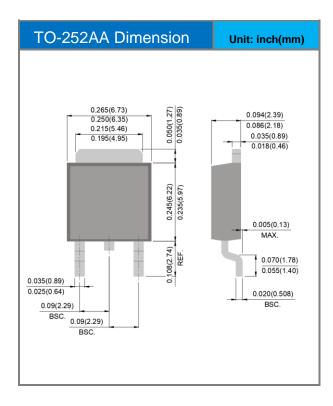
Fig.4 Typical Forward Characteristics

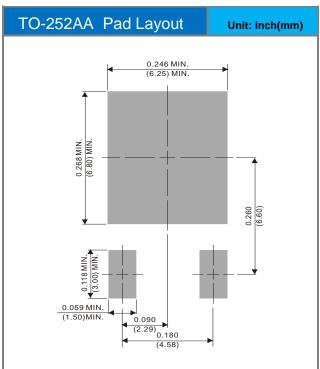


Product and Packing Information

Part No.	Package Type	Packing Type	Marking
MBR10H150CD-AU	TO-252AA	3K pcs / 13" reel	M10H150C

Packaging Information & Mounting Pad Layout







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